

HD74LVCZ240A

Octal Buffers / Line Drivers with 3-state Outputs

REJ03D0370-0300Z (Previous ADE-205-229A (Z)) Rev.3.00 Jul. 30, 2004

Description

The HD74LVCZ240A has eight inverter drivers with three state outputs in a 20 pin package. This device is an inverting buffer and has two active low enables $(1\overline{G} \text{ and } 2\overline{G})$. Each enable independently controls four buffers.

When V_{CC} is between 0 and 1.5 V, the device is in the high impedance state during power up or power down.

Low voltage and high-speed operation is suitable at battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

Features

- $V_{CC} = 2.7 \text{ to } 5.5 \text{ V}$
- All inputs V_{IH} (Max) = 5.5 V (@ V_{CC} = 0 to 5.5 V)
- All outputs V_0 (Max) = 5.5 V (@ V_{CC} = 0 V or output off state)
- Typical V_{OL} ground bounce < 0.8 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.0 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- High impedance state during power up and power down
- Power off disables outputs, permitting live insertion
- High output current ± 24 mA (@V_{CC} = 3.0 to 5.5 V)
- Ordering Information

| Part Name | Package Type | Package Code | Package Abbreviation | Taping Abbreviation (Quantity) |
|------------------|--------------------|--------------|-------------------------|--------------------------------|
| HD74LVCZ240AFPEL | SOP-20 pin (JEITA) | FP-20DAV | FP | EL (2,000 pcs/reel) |
| HD74LVCZ240ATELL | TSSOP-20 pin | TTP-20DAV | Т | ELL (2,000 pcs/reel) |

Note: Please consult the sales office for the above package availability.

Function Table

Inputs

| G | A | Output \overline{Y} |
|---|---|-----------------------|
| Н | X | Z |
| L | Н | L |
| L | L | Н |

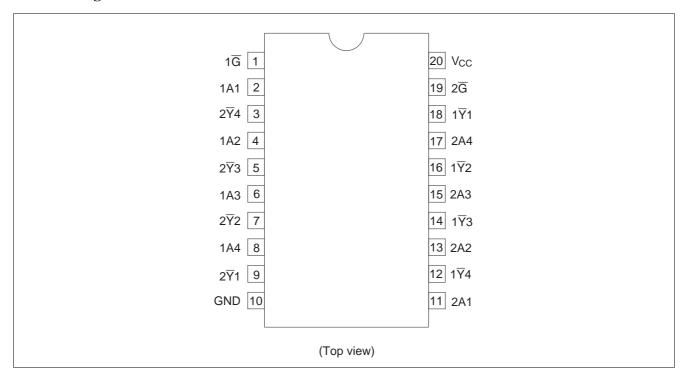
H: High level

L: Low level

X: Immaterial

Z: High impedance

Pin Arrangement



Absolute Maximum Ratings

| Item | Symbol | Ratings | Unit | Conditions |
|-------------------------------|-------------------------------------|------------------------------|------|-------------------------------------|
| Supply voltage | Vcc | -0.5 to 7.0 | V | |
| Input voltage | VI | -0.5 to 7.0 | V | |
| Output voltage | Vo | -0.5 to 7.0 | V | Output "Z" or V _{CC} : OFF |
| | | -0.5 to V _{CC} +0.5 | _ | Output "H" or "L" |
| Input diode current | I _{IK} | -50 | mA | V _I < 0 |
| Output diode current | I _{OK} | -50 | mA | V _O < 0 |
| Output current | I _O | ±50 | mA | |
| V _{CC} , GND current | I _{CC} or I _{GND} | ±100 | mA | |
| Storage temperature | Tstg | -65 to 150 | °C | |

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

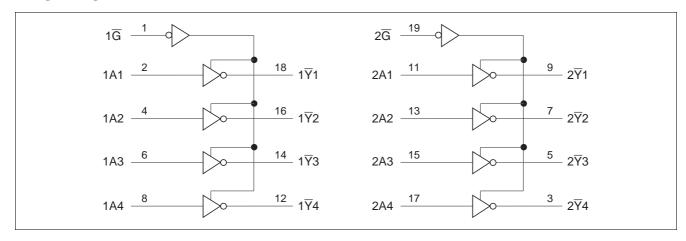
HD74LVCZ240A

Recommended Operating Conditions

| Item | Symbol | Ratings | Unit | Conditions |
|------------------------|---------------------------------|----------------------|--------|--|
| Supply voltage | Vcc | 2.7 to 5.5 | V | At operation |
| Input voltage | Vı | 0 to 5.5 | V | |
| Output voltage | Vo | 0 to 5.5 | V | Output "Z" or V _{CC} : OFF |
| | | 0 to V _{CC} | | Output "H" or "L" |
| Output current | I _{OH} | -12 | mA | V _{CC} = 2.7 V |
| | | -24 ^{*1} | | $V_{CC} = 3.0 \text{ to } 5.5 \text{ V}$ |
| | I _{OL} | 12 | mA | V _{CC} = 2.7 V |
| | | 24 *1 | | $V_{CC} = 3.0 \text{ to } 5.5 \text{ V}$ |
| Input rise / fall time | t _r , t _f | 0 to 6 | ns / V | |
| Operating temperature | Та | -40 to +85 | °C | |

Note: 1. Duty cycle ≤ 50%

Logic Diagram



Electrical Characteristics

 $Ta = -40 \text{ to } 85^{\circ}C$

| Item | Symbol | V _{CC} (V) | Min | Тур | Max | Unit | Test Conditions |
|--------------------------|-------------------|---------------------|------------------------|-------|----------------------|------|---|
| Input voltage | V _{IH} | 2.7 to 3.6 | 2.0 | _ | _ | V | |
| | | 4.5 to 5.5 | V _{CC} ×0 |).7 — | _ | _ | |
| | V _{IL} | 2.7 to 3.6 | _ | _ | 0.8 | V | |
| | | 4.5 to 5.5 | _ | _ | V _{CC} ×0.3 | _ | |
| Output voltage | V _{OH} | 2.7 to 5.5 | V _{CC} -0.2 — | | _ | V | $I_{OH} = -100 \mu A$ |
| | | 2.7 | 2.2 | _ | _ | _ | I _{OH} = −12 mA |
| | | 3.0 | 2.4 | _ | _ | _ | |
| | | 3.0 | 2.2 | _ | _ | _ | $I_{OH} = -24 \text{ mA}$ |
| | | 4.5 | 3.8 | _ | _ | _ | |
| | V _{OL} | 2.7 to 5.5 | _ | _ | 0.2 | V | I _{OL} = 100 μA |
| | | 2.7 | _ | _ | 0.4 | _ | I _{OL} = 12 mA |
| | | 3.0 | _ | _ | 0.55 | _ | I _{OL} = 24 mA |
| | | 4.5 | _ | _ | 0.55 | _ | |
| Input current | I _{IN} | 0 to 5.5 | _ | _ | ±5 | μΑ | $V_{IN} = 0 \text{ to } 5.5 \text{ V}$ |
| Off state output current | l _{OZ} | 2.7 to 5.5 | _ | _ | ±5 | μΑ | $V_{OUT} = 0$ to 5.5 V |
| | I _{OZPU} | 0 to 1.5 | _ | _ | ±5 | _ | $V_{OUT} = 0.5 \text{ to } 5.5 \text{ V},$ |
| | I _{OZPD} | 1.5 to 0 | _ | _ | ±5 | _ | Output enable = don't care |
| Output leak current | I _{OFF} | 0 | _ | _ | ±5 | μΑ | V_{IN} or $V_O = 5.5 \text{ V}$ |
| Quiescent supply current | Icc | 2.7 to 3.6 | _ | _ | 225 | μΑ | $V_{IN} = 3.6 \text{ to } 5.5 \text{ V}^{*1}, I_{O} = 0$ |
| | | 2.7 to 5.5 | _ | _ | 350 | _ | $V_{IN} = V_{CC}$ or GND |
| | ΔI_{CC} | 2.7 to 3.6 | _ | _ | 500 | μΑ | V_{IN} = one input at (V_{CC} –0.6) V, other inputs at V_{CC} or GND |
| Input capacitance | C _{IN} | 3.3 | _ | 3.4 | _ | pF | $V_{IN} = V_{CC}$ or GND |
| Output capacitance | Co | 3.3 | _ | 7.5 | _ | pF | V _{OUT} = V _{CC} or GND |
| | | | | | | | |

Note: 1. This applies in the disabled state only.

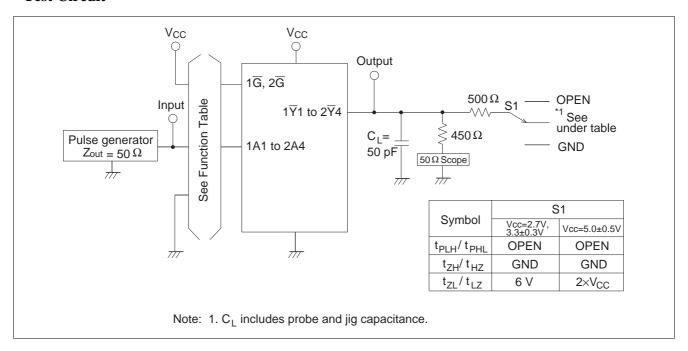
Switching Characteristics

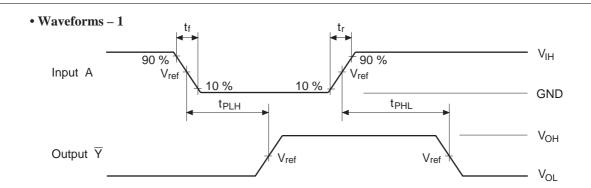
| | | | Ta = -40 to 85°C | | | | FROM | то |
|----------------------------|-------------------|---------------------|------------------|-----|-----|------|---------|----------|
| Item | Symbol | V _{CC} (V) | Min | Тур | Max | Unit | (Input) | (Output) |
| Propagation delay time | t _{PLH} | 2.7 | _ | _ | 7.5 | ns | А | Y |
| | t_{PHL} | 3.3±0.3 | 1.3 | _ | 6.5 | | | |
| | | 5.0±0.5 | _ | _ | 5.0 | | | |
| Output enable time | t _{ZH} | 2.7 | _ | _ | 9.0 | ns | G | Ÿ |
| | t_{ZL} | 3.3±0.3 | 1.1 | _ | 8.0 | | | |
| | | 5.0±0.5 | _ | _ | 6.5 | | | |
| Output disable time | t _{HZ} | 2.7 | _ | _ | 8.0 | ns | G | Ÿ |
| | t_{LZ} | 3.3±0.3 | 1.4 | _ | 7.0 | | | |
| | | 5.0±0.5 | _ | _ | 6.0 | | | |
| Between output pin skew *1 | t _{OSLH} | 2.7 | _ | _ | _ | ns | | |
| | toshl | 3.3±0.3 | _ | _ | 1.0 | | | |
| | | 5.0±0.5 | _ | _ | 1.0 | | | |

Note: 1. This parameter is characterized but not tested.

 $t_{\text{OSLH}} = |t_{\text{PLHm}} - t_{\text{PLHn}}|, \; t_{\text{OSHL}} = |t_{\text{PHLm}} - t_{\text{PHLn}}|$

Test Circuit





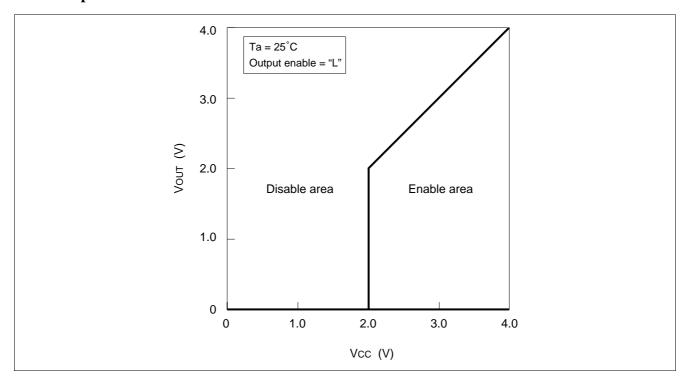
• Waveforms - 2 V_{IH} 90 % 90 % Input G V_{ref} 10 % GND t_{ZL} t_{LZ} $\approx V_{OH1}$ V_{ref} Waveform - A V_{OL} + 0.3 V $\rm V_{\rm OL}$ $t_{ZH} \\$ $t_{\text{HZ}} \\$ V_{OH} V_{OH}- 0.3 V Waveform - B V_{ref} ${\approx}V_{OL1}$

| TEST | Vcc=2.7V, 3.3±0.3V | Vcc=5.0±0.5V |
|------------------|-----------------------|--------------------|
| V_{IH} | 2.7 V | V _{CC} |
| V_{ref} | 1.5 V | 50%V _{CC} |
| V _{OH1} | 3 V | V _{CC} |
| V_{OL1} | GND | GND |

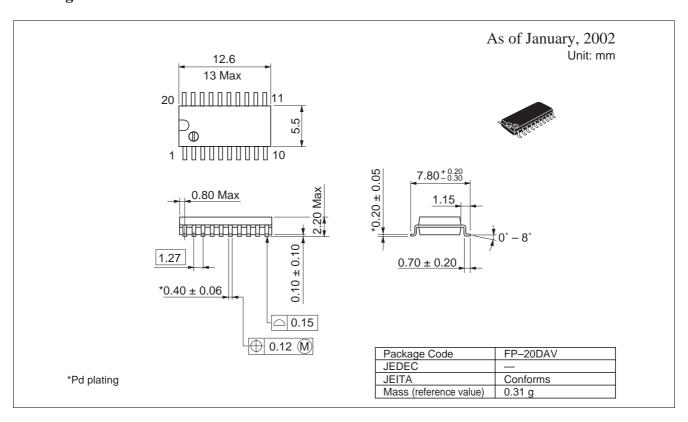
Notes: 1. Input waveform : PRR = 10 MHz, duty cycle 50%, t_r = 2.5 ns, t_f = 2.5 ns

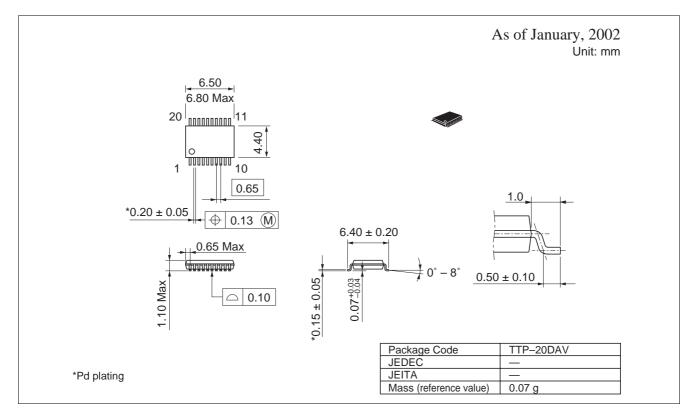
- 2. Waveform A shows input conditions such that the output is "L" level when enabled by the output control.
- 3. Waveform B shows input conditions such that the output is "H" level when enabled by the output control.

Power up / down Characteristics



Package Dimensions





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